

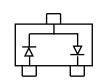


FEATURES

- Fast Switching Speed
- For General Purpose Switching Applications
- High Conductance









BAW56 Marking: A1

BAV70 Marking: A4

BAV99 Marking: A7

Maximum Ratings @T_A=25℃

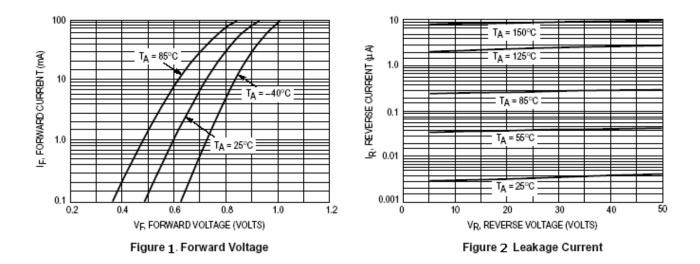
Parameter	Symbol	Limits	Unit
Reverse voltage	V _R	70	V
Forward Current	l _F	200	mA
Peak Forward Surge Current	I _{FM(surge)}	500	mA
Power Dissipation	PD	225	mW
Thermal Resistance Junction to Ambient Air	$R_{ extsf{ heta}JA}$	556	°C/W
Junction temperature	TJ	150	°C
Storage temperature range	T _{STG}	-55-150	°C

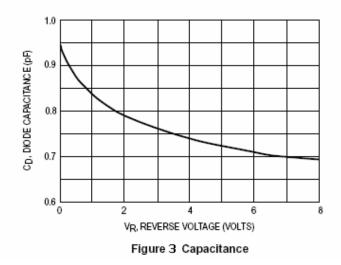
Electrical Characteristics @T_A=25℃

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Reverse Breakdown Voltage	V _R	70			V	Ι _R =100μΑ
Forward voltage	V _{F1}			0.715	V	I _F =1mA
	V _{F2}			0.855	V	I _F =10mA
	V _{F3}			1	V	l⊧=50mA
	V_{F4}			1.25	V	I _F =150mA
Reverse current	I _R			2.5	μA	V _R =70V
Capacitance between terminals	CT			1.5	pF	V _R =0,f=1MHz
Reverse recovery time	trr			6	ns	$I_F = I_R = 10 \text{mA},$
						$Irr= 0.1 \text{ x } I_{R}, R_{L} = 100\Omega$









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